

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceed the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
 - Class Q Military
 - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)

• Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.



74AC241, 74ACT241 Octal Buffer/Line Driver with 3-STATE Outputs

Features

- I_{CC} and I_{OZ} reduced by 50%
- Non-inverting 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs source/sink 24mA

Ordering Information

ACT241 has TTL-compatible inputs

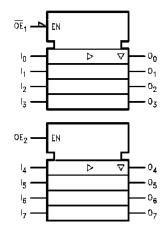
General Description

The AC/ACT241 is an octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus-oriented transmitter or receiver which provides improved PC board density.

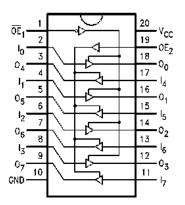
Package Number	Package Description
M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
	Number M20B M20D MTC20 M20B M20D

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number. Pb-Free package per JEDEC J-STD-020B.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
OE ₁	3-STATE Output Enable Input
OE ₂	3-STATE Output Enable Input (Active HIGH)
I ₀ –I ₇	Inputs
0 ₀ –0 ₇	Outputs

 $\mathsf{FACT}^{{\scriptscriptstyle\mathsf{T}}{\scriptscriptstyle\mathsf{M}}}$ is a trademark of Fairchild Semiconductor Corporation.

Truth Table

Inp	outs	Outputs
OE ₁	l _n	Pins 12, 14, 16, 18
L	L	L
L	Н	Н
Н	Х	Z

Inputs		Outputs
OE ₂	I _n	Pins 3, 5, 7, 9
Н	L	L
Н	Н	Н
L	Х	Z

H = HIGH Voltage Level L = LOW Voltage Level

X = Immaterial

Z = High Impedance

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	-0.5V to +7.0V
IIK	DC Input Diode Current	
	$V_{I} = -0.5V$	–20mA
	$V_{I} = V_{CC} + 0.5V$	+20mA
VI	DC Input Voltage	–0.5V to V _{CC} + 0.5V
I _{ОК}	DC Output Diode Current	
	$V_{O} = -0.5V$	–20mA
	$V_{O} = V_{CC} + 0.5V$	+20mA
Vo	DC Output Voltage	–0.5V to V _{CC} + 0.5V
Ι _Ο	DC Output Source or Sink Current	±50mA
I _{CC} or I _{GND}	DC V _{CC} or Ground Current per Output Pin	±50mA
T _{STG}	Storage Temperature	–65°C to +150°C
TJ	Junction Temperature	140°C

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	
	AC	2.0V to 6.0V
	ACT	4.5V to 5.5V
VI	Input Voltage	0V to V _{CC}
Vo	Output Voltage	0V to V _{CC}
T _A	Operating Temperature	-40°C to +85°C
$\Delta V / \Delta t$	Minimum Input Edge Rate, AC Devices:	125mV/ns
	$\rm V_{IN}$ from 30% to 70% of $\rm V_{CC}, \rm V_{CC}$ @ 3.3V, 4.5V, 5.5V	
$\Delta V / \Delta t$	Minimum Input Edge Rate, ACT Devices:	125mV/ns
	V_{IN} from 0.8V to 2.0V, V_{CC} @ 4.5V, 5.5V	

		V _{cc}		TA = -	+25°C	T _A = -40°C to +85°C	Units
Symbol	Parameter	(V)	Conditions	Тур.	G	uaranteed Limits	
V _{IH}	Minimum HIGH	3.0	$V_{OUT} = 0.1V$	1.5	2.1	2.1	V
	Level Input Voltage	4.5	or $V_{CC} - 0.1V$	2.25	3.15	3.15	
		5.5		2.75	3.85	3.85	
V _{IL}	Maximum LOW	3.0	$V_{OUT} = 0.1V$	1.5	0.9	0.9	V
	Level Input Voltage	4.5	or V _{CC} – 0.1V	2.25	1.35	1.35	
		5.5		2.75	1.65	1.65	1
V _{OH}	Minimum HIGH	3.0	I _{OUT} =50μA	2.99	2.9	2.9	V
	Level Output Voltage	4.5		4.49	4.4	4.4	1
		5.5		5.49	5.4	5.4	1
			$V_{IN} = V_{IL}$ or V_{IH} :				1
		3.0	$I_{OH} = -12mA$		2.56	2.46	
		4.5	I _{OH} =24mA		3.86	3.76	1
		5.5	$I_{OH} = -24 \text{mA}^{(1)}$		4.86	4.76	1
V _{OL}	Maximum LOW	3.0	I _{OUT} = 50μA	0.002	0.1	0.1	V
	Level Output Voltage	4.5		0.001	0.1	0.1	1
		5.5		0.001	0.1	0.1	1
			$V_{IN} = V_{IL}$ or V_{IH} :				1
		3.0	$I_{OL} = 12mA$		0.36	0.44	
		4.5	$I_{OL} = 24 \text{mA}$		0.36	0.44	1
		5.5	$I_{OL} = 24 m A^{(1)}$		0.36	0.44	1
I _{IN} ⁽³⁾	Maximum Input Leakage Current	5.5	$V_I = V_{CC}, GND$		±0.1	±0.1	μΑ
I _{OZ}	Maximum 3-STATE Leakage Current	5.5			±0.25	±2.5	μA
I _{OLD}	Minimum Dynamic	5.5	V _{OLD} = 1.65V Max.			75	mA
I _{OHD}	Output Current ⁽²⁾		V _{OHD} = 3.85V Min.			-75	mA
I _{CC} ⁽³⁾	Maximum Quiescent Supply Current	5.5	$V_{IN} = V_{CC}$ or GND		4.0	40.0	μA

1. All outputs loaded; thresholds on input associated with output under test.

2. Maximum test duration 2.0ms, one output loaded at a time.

3. $I_{\rm IN}$ and $I_{\rm CC}$ @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V $V_{\rm CC}.$

	Parameter	V _{CC} (V)		T _A = +25°C		T _A = -40°C to +85°C	
Symbol			Conditions	Typ. Guaranteed Limits		Units	
V _{IH}	Minimum HIGH	4.5	$V_{OUT} = 0.1V \text{ or}$	1.5	2.0	2.0	V
	Level Input Voltage	5.5	V _{CC} – 0.1V	1.5	2.0	2.0	
V _{IL}	Maximum LOW	4.5	$V_{OUT} = 0.1V \text{ or}$	1.5	0.8	0.8	V
	Level Input Voltage	5.5	V _{CC} – 0.1V	1.5	0.8	0.8	
V _{OH}	Minimum HIGH	4.5	$I_{OUT} = -50 \mu A$	4.49	4.4	4.4	V
	Level Output	5.5		5.49	5.4	5.4	
	Voltage		$V_{IN} = V_{IL} \text{ or } V_{IH}$:				
		4.5	$I_{OH} = -24mA$		3.86	3.76	
		5.5	$I_{OH} = -24 \text{mA}^{(4)}$		4.86	4.76	
V _{OL}	Maximum LOW Level Output Voltage	4.5	$I_{OUT} = 50 \mu A$	0.001	0.1	0.1	V
		5.5		0.001	0.1	0.1	
			$V_{IN} = V_{IL} \text{ or } V_{IH}$:				
		4.5	$I_{OL} = 24mA$		0.36	0.44	
		5.5	$I_{OL} = 24 m A^{(4)}$		0.36	0.44	
I _{IN}	Maximum Input Leakage Current	5.5	$V_I = V_{CC}, GND$		±0.1	± 1.0	μA
I _{OZ}	Maximum 3-STATE Leakage Current	5.5	$V_{I} = V_{IL}, V_{IH};$ $V_{O} = V_{CC}, \text{ GND}$		±0.25	±2.5	μA
I _{CCT}	Maximum I _{CC} /Input	5.5	$V_{I} = V_{CC} - 2.1V$	0.6		1.5	mA
I _{OLD}	Minimum Dynamic	5.5	$V_{OLD} = 1.65V$ Max.			75	mA
I _{OHD}	Output Current ⁽⁵⁾		V _{OHD} = 3.85V Min.			-75	mA
I _{CC}	Maximum Quiescent Supply Current	5.5	$V_{IN} = V_{CC}$ or GND		4.0	40.0	μA

Notes:

4. All outputs loaded; thresholds on input associated with output under test.

5. Maximum test duration 2.0ms, one output loaded at a time.

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AC Electrical Characteristics for AC

			T _A = +25°C, C _L = 50pF			$ \begin{array}{c} T_A = -40^\circ C \text{ to } +85^\circ C, \\ C_L = 50 p F \end{array} $		
Symbol	Parameter	V _{CC} (V) ⁽⁶⁾	Min.	Тур.	Max.	Min.	Max.	Units
t _{PLH}	t _{PLH} Propagation Delay, Data to Output	3.3	1.5	6.0	9.0	1.5	10.0	ns
		5.0	1.5	5.0	7.0	1.0	7.5	
t _{PHL}	PHL Propagation Delay, Data to Output	3.3	1.5	6.0	9.0	1.0	10.5	ns
		5.0	1.5	4.5	7.0	1.0	7.5	
t _{PZH}	Output Enable Time	3.3	1.5	6.5	12.5	1.0	13.0	ns
		5.0	1.5	5.5	9.0	1.0	9.5	
t _{PZL}	Output Enable Time	3.3	1.5	7.0	12.0	1.5	13.0	ns
		5.0	1.5	5.5	9.0	1.0	9.5	
t _{PHZ}	Output Disable Time	3.3	2.0	8.0	12.0	2.0	12.5	ns
		5.0	1.5	6.5	10.0	1.0	10.5	
t _{PLZ}	Output Disable Time	3.3	1.5	7.0	12.5	1.0	13.0	ns
		5.0	1.5	6.0	10.0	1.0	10.5	

Note:

6. Voltage range 3.3 is 3.3V \pm 3.3V. Voltage range 5.0 is 5.0V \pm 0.5V.

AC Electrical Characteristics for ACT

			T _A = +25°C, C _L = 50pF		$\label{eq:T_A} \begin{split} T_A = -40^\circ C \ to \ +85^\circ C, \\ C_L = 50 pF \end{split}$			
Symbol	Parameter	V _{CC} (V) ⁽⁷⁾	Min.	Тур.	Max.	Min.	Max.	Units
t _{PLH}	Propagation Delay, Data to Output	5.0	1.5	6.5	9.0	1.5	10.0	ns
t _{PHL}	Propagation Delay, Data to Output	5.0	1.5	7.0	9.0	1.5	10.0	ns
t _{PZH}	Output Enable Time	5.0	1.5	6.0	9.0	1.0	10.0	ns
t _{PZL}	Output Enable Time	5.0	1.5	7.0	10.0	1.5	11.0	ns
t _{PHZ}	Output Disable Time	5.0	1.5	8.0	10.5	1.5	11.5	ns
t _{PLZ}	Output Disable Time	5.0	2.0	7.0	10.5	1.5	11.5	ns

Note:

7. Voltage range 5.0 is 5.0V \pm 0.5V.

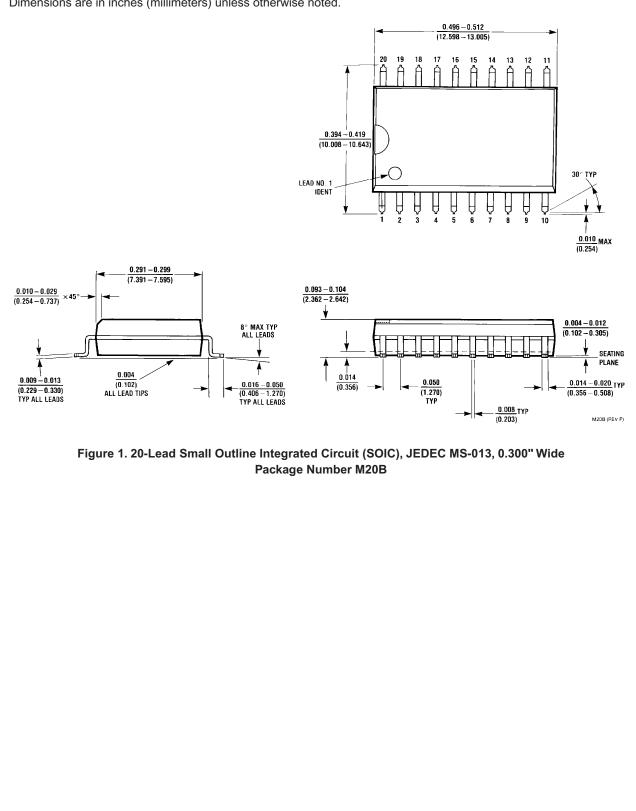
Capacitance

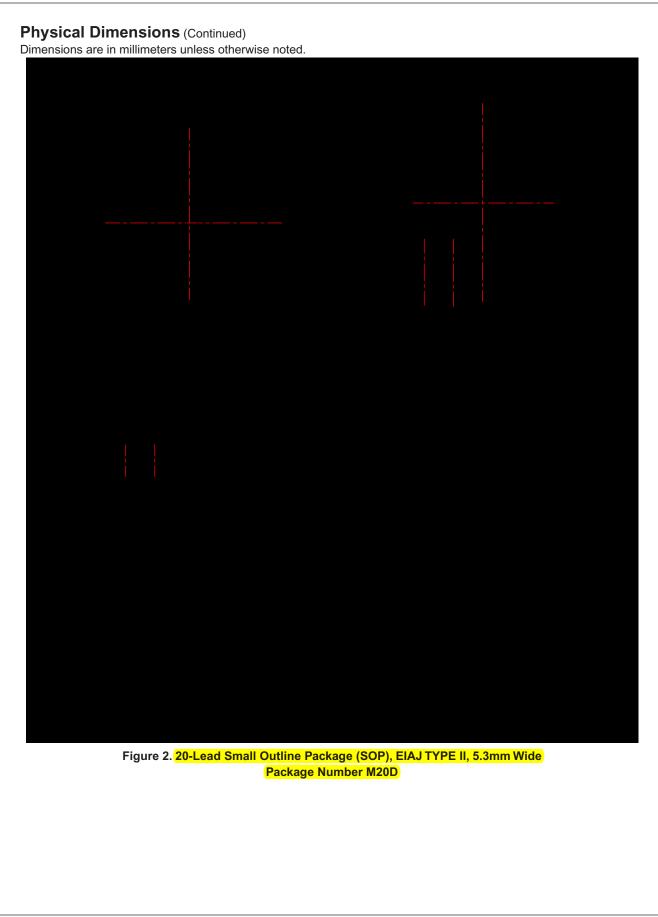
Symbol	Parameter	Conditions	Тур.	Units
C _{IN}	Input Capacitance	V _{CC} = OPEN	4.5	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 5.0V$	45.0	pF



Physical Dimensions

Dimensions are in inches (millimeters) unless otherwise noted.





Physical Dimensions (Continued) Dimensions are in millimeters unless otherwise noted.

Figure 3. 20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC20

